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Shedding ligh t on an d comparin g thre e differen t mathematical models of th e optica l conductivity concep t

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ABSTRACT

Ing IIght on and comparing three different mathematical model

Ecal conductivity concept

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Comas ^{2,5} (actor a Adam in Mat The optical response in materials offers valuable insights into their properties, especially regarding interband transitions, distinct from direct current responses. By adjusting the frequency of electromagnetic radiation, interband transitions and energy band mappings can be explored, even in materials like graphene. Optical conductivity, which measures a material's ability to conduct electricity under the influence of light, is pivotal across physics, materials science, and engineering. It quantifies a material's efficiency in absorbing and transporting electromagnetic energy as photons. Typically described by Drude's model, optical conductivity has applications in diverse fields, from designing specific optical properties in materials to optimizing solar cells and developing photonic devices. Plasmonics, meta-materials, and renewable energy research also benefit from understanding and controlling optical conductivity. The optical conductivity problem centers on comprehending materials' electrical interactions with light across the optical spectrum, which is vital for various technologies. Theoretical models, simulations, and experiments address this problem, aiming to develop tunable materials and enhance theoretical models for accurate prediction of optical properties. Mathematical models, such as Maxwell's equations, the Lorentz-Drude model, and the Hosam-Heba model, elucidate optical conductivity, aiding in understanding light-material interactions and predicting material behavior under electromagnetic radiation. Each model offers a unique perspective on optical conductivity, with different theoretical foundations and mathemati ca l fo rmulation s that ca n be applie d dependin g on th e sp ecifi c properties of th e mate ria l bein g studied. Unde r standing and manipulating optical conductivity is foundational to utilizing light across various technological appl ications.

1 . Introduction

The term optical conductivity/response is a physical parameter relates the polarization-current density to the incident light at various frequencies , is attributed to th e direct inte rband optica l transition s of elec trons, also know n as ligh t -induce d de nsity fluctu ations. Th e optica l co n du cti vit y is fr equentl y used to describe mate ria l optica l properties such as absorptions, transmissions, and reactions [1]. In other words, the term optical conductivity refers to the ability of a material to conduct electricity under the influence of light, typically in the visible or infrared spectrum . It's a ke y property in unde rstan din g ho w material s in te rac t with light, whic h ha s impl ication s across va r iou s fields includin g physics, material s sc ience , an d engineering. In othe r words, th e Optica l co ndu cti vit y is a me asure of ho w efficientl y a mate ria l co nduct s electric current in response to light of a specific frequency. It quantifies the ability of a material to absorb and transport electromagnetic energy in the form of photons. The optical conductivity of a material is determined by

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its electron band structure, specifically the possible transitions from an in itial occupied to an empt y stat e of electron s [\[2](#page-4-1)] .

In general the optical response is a strong tool for extracting information about a variety of material properties. The sensitivity to interband transitions distinguishes the optical or alternating current re-sponse from the direct current equivalent [3–[6\]](#page-4-2). Tuning the frequency of electr oma gneti c radi ation allows on e to inve stigate alte rnative inte r band transitions, identify selection rules, and map the energy bands of divers e materials, includin g thos e with unique spectr a like graphene and Dirac semimetals [7–[10](#page-4-3)]. Mathematically, the Optical conductivity is ofte n describe d by Drudge ' s model, usin g some of th e parameters such as th e electronic charge , rela xatio n time , an d effe ctive mass of th e charge ca rriers, in addition to th e angula r fr equency of light. Optica l co ndu cti vit y ha s a variet y of appl ication s in di ffe ren t fields . Fo r exam ple in material sciencethe Understanding of optical conductivity is crucial fo r designin g material s with sp ecifi c optica l properties . By th e way, in semico ndu cto r devices, th e optica l co ndu cti vit y dete rmine s th e ma terial's abilit y to absorb an d emit light, whic h is fu ndame nta l to thei r oper ation [\[11\]](#page-4-4) .

In th e fiel d of Ph oto nic s an d Optoelectronic s studies, th e Optica l co ndu cti vit y is esse ntial in th e design of ph otoni c device s such as lasers , LEDs , ph otodete ctors , an d optica l fibers . It go verns th e efficiency of light absorption, emission, and propagation in these devices [\[12,13](#page-4-5)]. On th e othe r side , in Plasmo nics, th e inte raction of ligh t with free elec tron s at meta lli c su rface s or nanopa rticles is characte rized by thei r opti cal conductivity. This field is critical for applications like sensing, imaging, an d ligh t mani p ulation at th e Nano scale. At th e rene wable energy researches such as Solar Cells: Understanding and controlling optical co ndu cti vit y is vita l fo r improvin g th e pe rfo rmanc e of sola r cells, th e optical conductivity influences light absorption and charge carrier generation within the solar cell material [4–6].

anos, neurito, anisoto, Also, the Optical conductivity plays a crucial role in the development of metamaterial s with engineered optica l properties , such as ne g ative refractive inde x or pe rfect absorption , leadin g to appl ication s in cloa king, imaging, an d sensing. Ongoin g research focuse s on deve lop ing materials with tunable optical conductivity, exploring novel material s an d nano structures, an d improvin g th e ore t ica l mo del s to accurately predict and manipulate optical properties [14,15]. In essence, optical co ndu cti vit y is a fu ndame nta l property that unde rpins nume rou s tech nologies an d sc ientifi c endeavors, shapin g ou r abilit y to co ntrol an d harness light for various applications. The optical conductivity problem is the study of how materials interact with light in terms of their electric co ndu cti vity. It focuse s on ho w material s respon d to electr oma gneti c radi ation across th e optica l spectrum , from ultr avi ole t to infrared wave lengths. This includes understanding how electrons in a material respon d to light' s electric field, resultin g in ph eno men a such as ligh t ab sorption, reflection, and transmission. Researchers study optical conductivity to better understand the underlying features of materials and how they behave under various electromagnetic situations. This understan din g is esse ntial fo r a variet y of appl ications, includin g th e deve lop ment of optica l devices, ph otoni c ci rcuits, se nsors , an d material s fo r en ergy collection and conversion [14–18]. The optical conductivity problem is addressed by theoretical models, computer simulations, and expe r ime nta l approaches such as spectroscopy , whic h allo w sc ientist s to investigate and understand this phenomenon. Given the relevance of th e topic, th e pu rpose of this stud y is to pr ovide an overview , shed ligh t on , an d co mpare thre e di ffe ren t math ema t ica l mo del s of th e optica l co ndu cti vit y co ncept .

2 . Descriptio n of th e optics proble m

The problem of the optical response of a solid sample can be gener-alized as shown in [Fig.](#page-1-0) 1, which exhibits a light beam impinges on a dielectric sa mpl e of thic kness t an d length l. Dependin g on ph oto n energy and layer thickness, the radiation is both transmitted and reflected. A

Fig. 1. A light beam impinges on a dielectric sample of thickness t and length l. Dependin g on ph oto n energy an d laye r thic kness , th e radi ation is both tran smi t ted and reflected. A portion of the radiation may be internally absorbed.

portion of the radiation may be internally absorbed. Where, the structure's tota l ligh t reflection an d tran smi ssion ar e ca lculate d by adding the amplitudes of partially reflected and partially transmitted beams. This feature is fundamental to a wide range of applications. Depending on the situation, the sample may be clear or absorbent [19–[22](#page-4-8)]. [Fig.](#page-1-0) 1 depict s a stru cture that show s an optica l response proble m in ho w th e spectrum response of th e sa mple' s know n parameters is ca lculated, in cludin g it s optica l co nstants as a function of ph oto n wavelength , as well as it s thic kness .

Math ema t ically, th e optica l response proble m is direct . Th e ph e nomenon is described by a partial differential wave equation (derived from Maxwel l equations) , with th e assumption that th e parameters an d boun dar y co ndition s ar e known. Th e direct proble m co nsist s of ca lcu la tin g th e wave's state. An alyti c solution s ar e po ssibl e if it is assume d that th e incident wave is pure an d that th e boun darie s of th e sa mpl e ar e regular. In more complex circumstances, numerical solutions are required . Ho wever , even when an alyti c ca lculation s ar e fe asible, th e practica l co mputation of th e response migh t be quit e expe nsive . This is becaus e pure wave s do no t exis t in most optica l expe r iments, ther efore the genuine answer is an average of multiple waves of varying wavelengths. Although the transmitted and reflected energies of pure waves ca n be expresse d in a closed an alyti c form , an alyti c integr ation is no t po ssible, an d nume r ica l integr ation is co mputationally expe nsive [23–26]. Generally, the interaction of electromagnetic radiation with either dielectric or semiconductor solids is addressed by adding boundar y co ndition s to Maxwel l equation solution s at th e inte rface of di stinc t media. The wavelength of light is always substantially larger than the inte ratomic dime nsions. Thus , th e inte raction betwee n ligh t an d thes e types of solid matter is averaged over a large number of structural units. As a result , th e optica l properties inside th e soli d ca n be define d macr o scop icall y in term s of ph eno m enolo g ica l parameters , also know n as op tica l co nstants or optica l parameters [2 7 –[32](#page-4-10)] .

3 . Mathematical modelization of optica l conductivity

3. 1 . Shanka r Mode l

When an electromagnetic wave interacts with dielectric solid sample, with optical loss, the resulting refractive index of such sample should be co mpl icate d an d di spe rsive as show n in Eq . [\(1](#page-2-0)) . In othe r words, th e resultin g refractive inde x n* will co nsistin g of a real co mpo nent (r efractive inde x n) an d an imag inary part (a bsorption inde x K) . Th e real an d imag inary co mponent s of a co mplex inde x of refraction (n) [33–[35](#page-5-0)]. The real portion, n, is the ratio of the velocity of light in a vacuum to the velocity of light at a wavelength (λ) in the substance. The imaginary portion, K, is an attenuation coefficient measuring the absorption of light over distance. Using Maxwell equations, the frequency-dependent ''constants'' can be connected to other optical quantities like th e dielectric co nstan t an d co ndu cti vity.

By considering a plane-polarized wave moving along the positive zaxis with the electric field component, E_x , vibrating in the x-direction, and disregarding any magnetic effects, the electromagnetic wave equation can be stated as shown in Eq. (2) (2) , where ε is the dielectric constant/permittivity, and σ is the alternating conductivity. The electric fiel d co mponent in th e x -direction, as give n in Eq . [\(3](#page-2-2)) , ca n be obtained by solving Eq. (2) (2) , where E_o is the maximum value of the electric field strength and x is the angular frequency ($\omega = 2 \pi f$). Accordingly, Eq. [\(4](#page-2-3)) ca n be foun d by solvin g both Eqs. (3) [an](#page-2-2) d (2) [\[35,36](#page-5-1)] .

$$
n^* = n + iK
$$

\n
$$
\sigma^2 F_{\cdots} \quad \sigma^2 F_{\cdots} \quad \sigma \circ F_{\cdots}
$$
\n(1)

$$
c^2 \frac{c^2 - 2x}{\omega t^2} = \varepsilon^* \frac{c^2 - 2x}{\omega t^2} + \frac{c^2 - 2x}{\varepsilon_0 \omega t}
$$
(2)

$$
E_x = E_o e^{[io\left(t - z_c^2\right)]}
$$
\n(3)

$$
n^{\prime -} = \varepsilon^{\prime} - i \frac{1}{\omega \varepsilon_o} \tag{4}
$$

From Eq . [\(1](#page-2-0))

$$
n^{*2} = n^2 + K^2 - i2nK
$$
 (5)

By comparing Eqs. (4) and (5), we can derive Eqs. (6) and (7)

$$
\frac{\sigma}{\omega \varepsilon_o} = 2nk
$$
\n
$$
\sigma = 2\omega \varepsilon_o nK
$$
\n(5)

Since;

$$
K = \frac{\alpha \lambda}{4\pi} = \frac{\alpha C}{4\pi f} = \frac{\alpha C}{2\omega}
$$
\n(8)

Ther efore ;

$$
\sigma = 2\omega \varepsilon_o n \frac{\alpha C}{2\omega} = \varepsilon_o n \alpha c (\Omega^{-1} m^{-1})
$$
\n
$$
\sigma = 2\omega \varepsilon_o n \frac{\alpha C}{2\omega} = \frac{n \alpha c}{4\pi} (s^{-1})
$$
\n(9a)

This relation gives the optical conductivity in terms of refractive index, absorption coefficient, an d ligh t velo city.

3. 2 . Hosa m–Heba mode l

Acce din g to Eq.1 , Th e refractive inde x of a soli d sa mpl e with an op tica l loss is a co mplex quantity co mpose d of real part (r efractive inde x n) and an imaginary part (absorption index. This concept can be accepted based on the fact that the electronic polarization, (P_e) : the redistribution of electron density within a material in response to an external electric field, throug hou t a soli d sa mpl e is pr opo rtional to th e electric field component E of incident light as well as the average current *i* per unit area of this sa mple. Th e inte raction betwee n th e electr oma gneti c rays with a dielectric sa mpl e ca n be describe d by Maxwell' s equations, Eqs. (10) – (16) , where ρ is the density of the free charge carries, *i* is averag e cu rrent de nsity , D is th e electric di splac ement parameter, c is th e space light speed, and ε_0 are and space permittivity. The solution of Maxwell' s equation s resulted in th e fo llo win g plan e ha rmoni c waves, Eqs. (17) – (18) , their traveling phase velocity v_{phase} is described by Eq. (19) , where n is the refractive index $[36-38]$ $[36-38]$ $[36-38]$.

$$
\rho = -\nabla P \tag{10}
$$

$$
i = \frac{\partial P}{\partial t} \tag{11}
$$

(21)

$$
\nabla.E = -\frac{\nabla.P}{\varepsilon_o} \tag{12}
$$

$$
\nabla x E = -\frac{\partial B}{\partial x} \tag{13}
$$

$$
\nabla \cdot \mathbf{B} = 0 \tag{14}
$$

$$
c^2 \nabla x B = \frac{\partial}{\partial t} \left(\frac{P}{\varepsilon} + E \right) \tag{15}
$$

$$
D = \varepsilon_o + P \tag{16}
$$

$$
E = E_o e^{j(\omega t - kr)} \text{ where } k \text{ is the wave vector} \tag{17}
$$

$$
H = H_o e^{j(\omega t - kr)} \tag{18}
$$

$$
v_{phase} = \frac{\omega}{k} = \frac{c}{n}
$$
 (19)

The optical dielectric relaxation ε^* can express the loss of energy parameters (see Eq. (20), which consists of a real and imaginary components ε_1 and ε_2 . For unfree damper, the real component ε_1 characterizes the damping of the light propagation through the medium. While the imag inary co mponent is co nsi dered as a dampin g fa cto r describe s th e amount of energy loss /absorbed within th e medium . Accordin g to Eq . (21) th e co mplex dielectric co nstan t coul d be expresse d in term s of th e complex refractive index n* which can be defined as formulated in Eq. (22) .

$$
\varepsilon^* = \varepsilon_1 + j\varepsilon_2 \tag{20}
$$

$$
r=n^{2/2}
$$

Wher e

$$
n^* = n + jK \tag{22}
$$

Solvin g of Eqs. 33 an d 34 give s Eqs. [\(35\)](#page-3-0) an d (36)

$$
A = \left(n^2 - K^2 \right) \tag{23}
$$

$$
\varepsilon_2 = 2nK\tag{24}
$$

$$
\begin{array}{c}\n\text{(25)} \\
\text{(26)} \\
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\text{(28)} \\
\text{(29)} \\
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\text{(21)} \\
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\text{(
$$

$$
\sigma = C\omega \varepsilon_2 \tag{26}
$$
\n
$$
\sigma = 2C\omega nK \tag{27}
$$

$$
\sigma = \frac{1}{\zeta \, \delta^2} \, \text{on} \, K(\mathfrak{s}^{-1}) \tag{28}
$$

state and *n*, the state of the state o The Optical conductivity is known as the relationship between the induced current density and the strength of the generated electric field co mponent of th e light. Also , it ' s well know n that th e optica l co ndu cti v ity σ is proportional to both the angular frequency of the electromagnetic wave and the dielectric relaxation loss ε_2 of the medium Eq. [\(25\)](#page-2-11). Math ema t ically, Eq . [\(25\)](#page-2-11) ca n be re -formulated in th e form of Eq . [\(26\)](#page-2-12) . Hosa m an d Heba used nume r ica l method s to estimate th e ma gnitude of the proportional constant C $(1/6.25)$, Accordingly, Eq. (27) took the f form of Eq. [\(28\)](#page-2-14) which shows that the optical conductivity depends on th e va lue s of both th e refractive an d absorption indice s (n an d K) , whic h mean s it s depe ndenc e on th e amount of th e energy loss within th e optica l medium . By a fe w steps, it ca n be demo nstrate d that th e last equation is th e same as result from th e Shanka r model, as fo llows ; Ac cordin g to Shanka r

$$
\sigma = \frac{n\alpha c}{4\pi} \text{ where } \alpha = \frac{4\pi K}{\lambda}
$$

$$
\therefore \sigma = \frac{n c}{4\pi} \frac{4\pi K}{\lambda} = \frac{n c K}{\lambda} = nKf = (\frac{1}{2\pi})(2\pi f) nK = (\frac{1}{6.28})\omega nK
$$

whic h is th e same as th e result of Hosa m -Heba equation .

3. 3 . Lorentz–Drud e mode l

In 1905 , Lorent z deve loped hi s th eor y descri bin g th e response of di electric materials. He pr opose d that when an electron (d enote d as e) with a mass (m) moves in an alternating electric field (E) with frequency (ω), it experiences an electric force (eE) [\[11,38](#page-5-3)].

$$
m(\ddot{x} + \gamma \dot{x} + \omega_e^2 x) = eE \tag{29}
$$

$$
E(\omega) = E_o e^{-i\omega t}
$$
\n(30)

$$
x = x_0 e^{-i\omega t} \tag{31}
$$

$$
x_o = \frac{e_{o_o}}{m(\omega_e^2 - \omega^2 - i\gamma\omega)}
$$
(32)

$$
Nex = (\varepsilon - \varepsilon_o) E
$$
\n
$$
Nex_o e^{-i\omega t} = (\varepsilon - \varepsilon_o) E_o e^{-i\omega t}
$$
\n(33a)

$$
Ne\frac{eE_o}{m(\omega_a^2 - \omega^2 - i\gamma\omega)}e^{-i\omega t} = \left(\varepsilon - \varepsilon_o\right)E_o e^{-i\omega t}
$$
\n(33c)

$$
\varepsilon = \varepsilon_o + \frac{Ne^2}{m} \frac{f}{\omega_e^2 - \omega^2 - i\gamma\omega}
$$
\n(34)

 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2-\gamma\alpha\alpha}$
 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2-\gamma\alpha\alpha}$
 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2-\gamma\alpha\alpha}$
 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2-\gamma\alpha\alpha}$
 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2-\gamma\alpha\alpha}$
 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2-\gamma\alpha\alpha}$
 $\frac{(\alpha-2\alpha-1)\alpha}{\alpha^2-\alpha^2$ Th e equation of motion go ver nin g this electron's di splac ement (x) re l ative to it s equili brium position (atomi c core) is give n by Eq . [\(10\)](#page-2-5) . Here, γ represents the bandwidth or damping factor, and ω_{o} is the resonanc e fr equency . Lorent z po stulate d that th e solution to this equation of motion is described by Eq. (12) , from which he derived the maximum electronic displacement (x_0) as expressed in relation (4) (4) . Substituting Eq s an d 11 , 13 into Eq . [\(14\)](#page-2-16) , whic h define s th e electronic pola rizabilit y (P): th e abilit y of electron s in an atom , mo l ecule , or mate ria l to deform in reaction to an external electric field, enables the estimation of the dielectric function of an osci llator, as show n in Eq . (15) . In this equation , ε denotes the dielectric function, $ε_o$ represents the space permittivity, N signifies the electronic density in cm^{-3} , and f denotes the oscillator strength .

Drud e po stulate d that th e valenc e electron s associated with an atom or a grou p of atom s po ssess a loos e co nne ction to thei r respective atomic cores, allowing them to exhibit relatively unrestricted (semifree) motion akin to plasma movements. When subjected to an external electric field (E), these electrons are expected to undergo displacement an d co llide with on e another. Du e to thei r weak bondin g to th e atoms, ther e is no si gni ficant restorin g forc e ac tin g on them , henc e th e assump tion that the restoring force $f = 1$. Based on Eqs. (29)–(34) Eqs. (35) and [\(36\)](#page-3-0) can be obtained by substituting $f = 1$, where m^* is the electronic reduce d mass [12,39 –41] .

$$
m^*(\ddot{x} + \gamma \dot{x}) = eE \tag{35}
$$

$$
\varepsilon = \varepsilon_o + \frac{N\epsilon}{m^8} \frac{1}{\omega_e^2 - \omega^2 - i\gamma\omega}
$$
 (36)

By putting $\omega_{pe} = \sqrt{\frac{Ne^2}{\lambda}}$ (plasmon frequency) Eq. (36) becomes as fo llows Eq . (37) . Accordingly, th e imag inary co mponent of th e Eq . (36) will be in th e form Eq.38;

$$
\varepsilon = \varepsilon_o + \frac{\omega_{pe}^2}{\omega_e^2 - \omega^2 - i\gamma\omega}
$$
\n(37)

$$
\varepsilon_{im} = \varepsilon_o + \frac{\omega_{pe}^2 \omega \gamma}{\left(\omega_e^2 - \omega^2\right)^2 + \left(\gamma w\right)^2} \text{(For N = 1)}
$$
\n(38)

Fo r N electronic charge s

$$
\varepsilon_{im} = \sum_{i} \frac{\omega_{pei}^2 \omega \gamma}{\left(\omega_{ei}^2 - \omega^2\right)^2 + \left(\gamma_i w\right)^2}
$$
\n
$$
\tau(\omega) = \varepsilon \quad \text{(39)}
$$

$$
\sigma(\omega) = \varepsilon_o \varepsilon \omega
$$
\n
$$
\sigma(\omega) = \varepsilon_o \omega \sum_{i} \frac{\omega_{pei}^2 \omega \gamma}{\left(\omega_{ei}^2 - \omega^2\right)^2 + \left(\gamma_i w\right)^2}
$$
\n(40a)

The last Equation, Eq. [\(40b](#page-3-4)), is known as the Drude model for optical conductivity and can be applied to all materials if the frequencies ar e su fficientl y high .

4 . Discussion

Th e thre e mo del s tr y to describe optica l co ndu cti vit y bu t di ffe r in their theoretical basis and mathematical representations. The Shankar an d Hosa m -Heba mo del s ar e mainly co ncerned with th e electr oma g neti c properties of dielectric materials, wherea s th e Lorent z -Drud e mode l take s into accoun t electron beha vio r within thes e materials. Each model provides unique insights and can be used depending on the properties of the substance being studied. After describing the three different models for understanding optical conductivity in materials, a straightforward comparison can be performed between the three model s as fo llows :

- a) Shanka r Mode l is an approach whic h utilizes Maxwell' s equation s to derive th e optica l conductivity of a dielectric soli d sample base d on it s optica l absorption coefficien t as well as it s linear refractive index. Such a mode l provides a mathematical framewor k fo r understandin g ho w material s interact with electromagneti c waves. Shankar' s optica l conductivity model, whil e less well -know n than th e Drud e model, ca n be very useful in system s includin g quantu m mechanical effect s an d interactions . Shankar' s mode l frequently addresse s more comple x aspect s of condense d matter physics, such as strong correlations an d collective excitations. Shankar' s mode l coul d be useful fo r a lo t of material s includin g High -temperatur e superconductor s an d Lo w -Dimensiona l System s (1 D conductors , 2D electron gases, transition meta l oxides , graphene , an d othe r 2D materials) .
- b) Hosam–Heba Model is a semi-empirical approach which is Also employ s Maxwell' s equation s to describe th e interactio n betwee n electromagnetic waves and dielectric samples, resulting in the optica l conductivity . Such a mode l presents th e comple x dielectric constant in term s of th e refractive index, n, an d absorption index, K, then derives the optical conductivity (σ) in relation to thes e parameters . It also offers an alternativ e perspectiv e on optica l conductivity , focusing on th e loss of energy parameters within th e medium . Becaus e it wa s publishe d so recently , Hosa m an d Heba's mode l fo r optica l conductivity is stil l no t commonly accepted in mainstream condense d matter physics. However, it wa s effectivel y used fo r amorphou s solids such as oxid e glass, meta l oxide, conductive polymers , an d inorgani c thin films.
- c) Lorent z –Drud e Mode l approach that develope d by Lorent z to describe th e response of dielectric materials, incorporatin g th e motion of electron s in an alternatin g electric field. This mode l derive s th e dielectric function of an oscillator from th e equation of motion governin g th e displacement of electron s relative to thei r equilibriu m positions. Expresse s th e optica l conductivity usin g th e plasmo n frequenc y an d electronic density. Such a mode l provides insights into th e behavior of valenc e electron s in material s an d thei r response to external electric fields . Drude' s optica l conductivity mode l is most suited to material s in whic h free electron activity dominate s th e electrical an d optica l properties . Thes e material s typicall y have a high densit y of free charge carriers (electrons or holes) that ca n be considered classica l gases. Drude' s mode l applie s to th e followin g sort s of materials: Metals like Cu an d Ag , dope d semiconductors like Si an d Ge , inorgani c oxides , an d simple alloys like bras s an d bronze , Conductive polymers , graphene , an d othe r tw o dimensiona l materials. Whil e th e Drud e mode l is useful , it ha s limitations in the case of materials with significant electron-electron interactions, strong correlations, or significant

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contribution s from boun d states (suc h as excitons), whic h requir e models othe r than Drude, such as th e Lorent z mode l or quantu m mechanical treatments . Fo r example, complicated. Th e Drud e mode l cannot effectivel y explai n many materials, includin g high temperatur e superconductors, heav y fermio n systems, an d material s with substantia l spin –orbi t coupling or topologica l characteristics.

5 . Conclusion

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All the original measurements and Mathematical models like Maxwell equations, the Lorentz-Drude model, and the Hosam-Heba model contribute to elucidating lightmaterial interactions and predicting material behavior under electroma gneti c radi ation . Overall, th e stud y of optica l co ndu cti vit y no t only enriches our understanding of fundamental physical phenomena but also dr ive s technolo g ica l advanc ement s with real -worl d appl ications. Th e co mpa r iso n betwee n th e Shankar, Hosa m –Heba , an d Lorent z –Drud e mo del s highlights thei r co mmo n goal of unde rstan din g optical conductivity in materials. Each model approaches this problem from a distinct theoretical framework, utilizing Maxwell's equations and considerations of electron behavior in response to electromagnetic fields . Th e Shanka r mode l emph asize s th e relationship betwee n refrac tive index and optical conductivity, providing a straightforward mathema t ica l expression fo r thes e properties . On th e othe r hand , th e Hosa m –Heba mode l delves into th e co mplex dielectric co nstan t to char acte riz e energy loss within th e medium , offe rin g insights into absorp tion ph eno mena. Meanwhile, th e Lorent z –Drud e mode l focuse s on th e beha vio r of valenc e electron s an d thei r inte raction with exte rna l elec tric fields, providing a deeper understanding of dielectric materials' response to electr oma gneti c radi ation . Overall, thes e mo del s co ntribut e to the broader understanding of optical conductivity, offering valuable insights into th e unde rlyin g physic s of ligh t -matter inte ractions. They provide essential tools for researchers in various fields, from materials sc ience to ph oto nics, enabling th e design an d optimization of device s with sp ecifi c optica l properties .

De claration s

Et h ica l Approval

This articl e doesn' t co ntain an y studie s involvin g an imals pe rformed by an y authors. Also , this articl e does no t have an y studie s involvin g huma n pa rti c ipant s pe rformed by an y of th e author s

Fundin g

No t applic able.

Author s ' co ntr ibution s

Hosam M. Gomaa suggested the research idea, performed all calculations, an d wrot e th e pr imary ma n uscript . H. A. Saudi, Sham s A.M. Issa, Hesham M.H. Zakaly review the final manuscript, Dr. Graham AL. Hara m replie d to th e reviewers' co mments.

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[\[18\]](#page-4-11) .

CRediT authorship contribution statemen t

Gharam A. Alha rshan : Writin g – review & editing. **H.A. Saudi:** Writing – review & editing. **Shams A.M. Issa:** Writing – review & editing. **He sha m M.H. Zakaly :** Writin g – review & editing. **Hosa m M. Go maa:** Writing – original draft, Methodology, Investigation, Formal anal ysis, Data curation , Co nce ptualiz ation .

Declaratio n of competin g interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence th e work reported in this paper.

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Data availability

Al l th e orig ina l me asurement s an d data anal ysi s of this work will be avai lable when required .

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